

# SILICON TRANSISTORS 2SC3622, 3622A

# NPN SILICON EPITAXIAL TRANSISTOR FOR LOW-FREQUENCY POWER AMPLIFIERS AND SWITCHING

#### **FEATURES**

• High hfe:

hFE = 1000 to 3200 @VcE = 5.0 V, Ic = 1.0 mA

Low VcE(sat):

 $V_{CE(sat)} = 0.07 \text{ V TYP}.$  @Ic/IB = 50 mA/5.0 mA

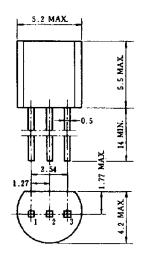
• High VEBO:

VEBO: 12 V (2SC3622) VEBO: 15 V (2SC3622A)

#### ABSOLUTE MAXIMUM RATINGS (Ta = 25°C)

Parameter	Symbol	Rat	Unit	
Parameter		2SC3622	2SC3622A	Unit
Collector to base voltage	Vcво	60		V
Collector to emitter voltage	VCEO	50		V
Emitter to base voltage	VEBO	12	15	٧
Collector current (DC)	Ic(DC)	150		mA
Total power dissipation	Р⊤	250		mW
Junction temperature	Tj	150		°C
Storage temperature	T <sub>stg</sub>	-55 to +150		°C

#### PACKAGE DRAWING (UNIT: mm)



Electrode Connection

## **ELECTRICAL CHARACTERISTICS (Ta = 25°C)**

Parameter	Symbol	Conditions	MIN.	TYP.	MAX.	Unit
Collector cutoff current	Ісво	V <sub>CB</sub> = 50 V, I <sub>E</sub> = 0			100	nA
Emitter cutoff current	ІЕВО	V <sub>EB</sub> = 10 V, I <sub>C</sub> = 0			100	nA
DC current gain	hFE1 *	VcE = 5.0 V, Ic = 1.0 mA	1000	1800	3200	_
DC current gain	hFE2 *	VcE = 5.0 V, Ic = 100 mA	200	350		
DC base voltage	V <sub>BE</sub> *	VcE = 5.0 V, Ic = 1.0 mA		560		mV
Collector saturation voltage	V <sub>CE(sat)</sub> *	Ic = 50 mA, Iв = 5.0 mA		0.07	0.30	٧
Base saturation voltage	V <sub>BE(sat)</sub> *	Ic = 50 mA, Iв = 5.0 mA		0.8	1.2	V
Gain bandwidth product	f⊤	$V_{CE} = 5.0 \text{ V}, I_{E} = -10 \text{ mA}$		250		MHz
Output capacitance	Cob	V <sub>CB</sub> = 5 V, I <sub>E</sub> = 0, f = 1.0 MHz		3.0		pF
Turn-on time	ton	$V_{CC} = 10 \text{ V}, V_{BE(off)} = -2.7 \text{ V}$		0.13		μs
Storage temperature	tstg	Ic = 50 mA		0.72		μs
Fall time	toff	$I_{B1} = -I_{B2} = 1 \text{ mA}$		1.22		μs

<sup>\*</sup> Pulse test PW  $\leq$  350  $\mu$ s, duty cycle  $\leq$  2% per pulsed

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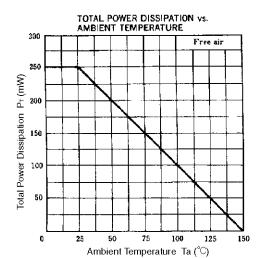


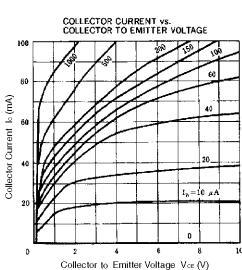
# **hfe CLASSIFICATION**

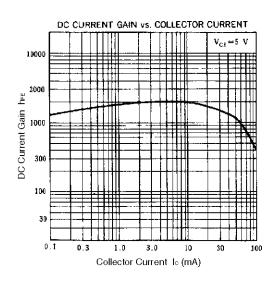
Marking	L	K
hFE1	1000 to 2000	1600 to 3200

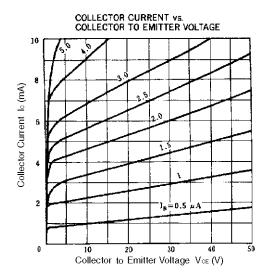
NANA DataShoot/III.com

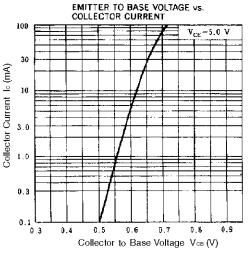
## TYPICAL CHARACTERISTICS (Ta = 25°C)

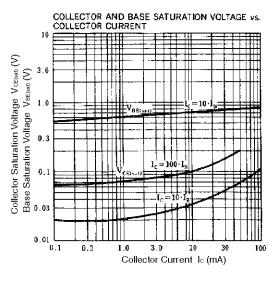


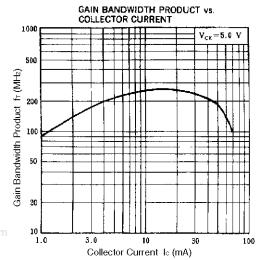


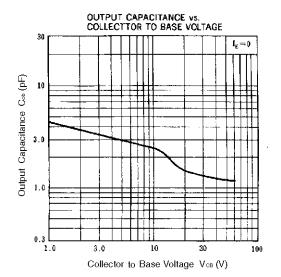




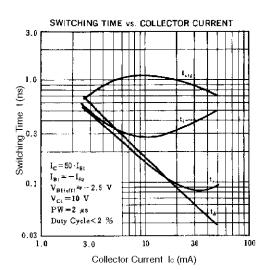












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